

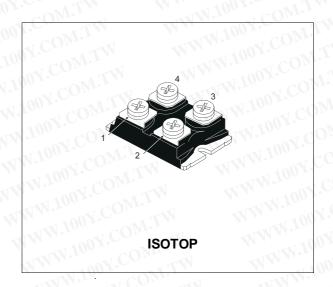
ESM6045DV

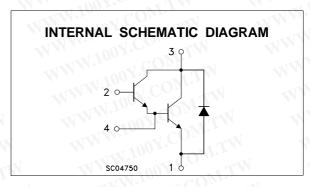
NPN DARLINGTON POWER MODULE

- HIGH CURRENT POWER BIPOLAR MODULE
- VERY LOW Rth JUNCTION CASE
- SPECIFIED ACCIDENTAL OVERLOAD AREAS
- ULTRAFAST FREEWHEELING DIODE
- FULLY INSULATED PACKAGE (UL COMPLIANT)
- EASY TO MOUNT
- LOW INTERNAL PARASITIC INDUCTANCE

INDUSTRIAL APPLICATIONS:

- MOTOR CONTROL
- SMPS & UPS
- DC/DC & DC/AC CONVERTERS
- WELDING EQUIPMENT





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CEV}	Collector-Emitter Voltage (V _{BE} = -5 V)	600	V
V _{CEO(sus)}	Collector-Emitter Voltage (I _B = 0)	450	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)	ZW.Too CON	V
Ic	Collector Current	84	Α
Ісм	Collector Peak Current (tp = 10 ms)	126	Α
lΒ	Base Current	8 11 8	Α
I _{BM}	Base Peak Current (tp = 10 ms)	16	Α
P _{tot}	Total Dissipation at T _c = 25 °C	250	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Four Terminals to Exernal Heatsink		V
T _{stg}	Storage Temperature	-55 to 150	°C
T _i	Max. Operating Junction Temperature	150	°C

September 2003 1/8

ESM6045DV

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THERMAL DATA

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THERMAL	_ DATA	WWW.TOOX.COM.	-		
R _{thi-case}	Thermal Resistance	Junction-case (transistor)	Max	0.5	°C/W
R _{thj-case}	Thermal Resistance	Junction-case (diode) Case-heatsink With Conductive	Max	1.2	°C/W
W. J.	Grease Applied	MAN. Too COM.	Max	0.05	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

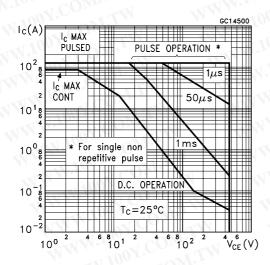
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
ICER#	Collector Cut-off Current ($R_{BE} = 5 \Omega$)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ $T_j = 100$ °C		MM	1.5 22	mA mA
I _{CEV} #	Collector Cut-off Current (V _{BE} = -5)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ $T_j = 100$ °C	N	WV	1 15	mA mA
I _{EBO} #	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V		W.	1	mA
Vceo(sus)*	Collector-Emitter Sustaining Voltage (I _B = 0)	$I_{C} = 0.2 \text{ A}$ $L = 25 \text{ mH}$ $V_{clamp} = 450 \text{ V}$	450		NWW	(100)
h _{FE} *	DC Current Gain	I _C = 70 A V _{CE} = 5 V	William	120	77.7	W.100
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$I_{C} = 50 \text{ A}$ $I_{B} = 1 \text{ A}$ $I_{C} = 50 \text{ A}$ $I_{B} = 1 \text{ A}$ $T_{j} = 100 ^{\circ}\text{C}$ $I_{C} = 70 \text{ A}$ $I_{B} = 4 \text{ A}$ $I_{C} = 70 \text{ A}$ $I_{B} = 4 \text{ A}$ $T_{j} = 100 ^{\circ}\text{C}$	OM.TV	1.2 1.6 1.35 1.7	2	V V V
V _{BE(sat)} *	Base-Emitter Saturation Voltage	I _C = 70 A I _B = 4 A I _C = 70 A I _B = 4 A T _j = 100 °C	COM	2.3 2.4	3	V
di _C /dt	Rate of Rise of On-state Collector	$V_{CC} = 300 \text{ V}$ $R_C = 0$ $t_p = 3 \mu s$ $I_{B1} = 1.5 \text{ A}$ $T_j = 100 ^{\circ}\text{C}$	375	450		A/μs
V _{CE} (3 μs)••	Collector-Emitter Dynamic Voltage	$V_{CC} = 300 \text{ V}$ $R_C = 6 \Omega$ $I_{B1} = 1.5 \text{ A}$ $T_j = 100 ^{\circ}\text{C}$	00Y.C	6	9	V
V _{CE} (5 μs)••	Collector-Emitter Dynamic Voltage	$V_{CC} = 300 \text{ V}$ $R_C = 6 \Omega$ $I_{B1} = 1.5 \text{ A}$ $T_j = 100 ^{\circ}\text{C}$	100X	COM	4.5	V
ts t _f t _c	Storage Time Fall Time Cross-over Time	$\begin{array}{l} I_{C} = 50 \; A V_{CC} = 50 \; V \\ V_{BB} = -5 \; V R_{BB} = 0.3 \; \Omega \\ V_{clamp} = 450 \; V I_{B1} = 1 \; A \\ L = 0.05 \; mH T_{j} = 100 \; ^{\circ}C \end{array}$	M.100	3.5 0.3 0.8	5.5 0.5 1.7	μs μs μs
V _{CEW}	Maximum Collector Emitter Voltage Without Snubber	$\begin{split} & _{CWoff} = 84 \text{ A} _{B1} = 4 \text{ A} \\ & _{VBB} = -5 \text{ V} _{VCC} = 50 \text{ V} \\ & _{L} = 0.03 \text{ mH} _{RBB} = 0.3 \Omega \\ & _{j} = 125 ^{\circ}\text{C} \end{split}$	450	100X	COM.T	
V _F *	Diode Forward Voltage	I _F = 70 A T _j = 100 °C	WW	1.6	1.9	V
I _{RM}	Reverse Recovery Current	$V_{CC} = 200 \text{ V}$ $I_F = 70 \text{ A}$ $di_F/dt = -375 \text{ A}/\mu\text{s}$ $L < 0.05 \mu\text{H}$ $T_j = 100 ^{\circ}\text{C}$	WW	38	45	A

^{*} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 %

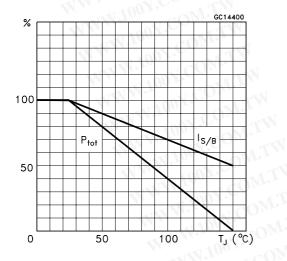
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 $_{H}$ see lest circuits in databook introduction. To evaluate the conduction losses of the diode use the following equations: $V_F=1.5+0.0055\ I_F \qquad P=1.5\ I_{F(AV)}+0.0055\ I^2_{F(RMS)}$ WWW.100Y.COM.TW

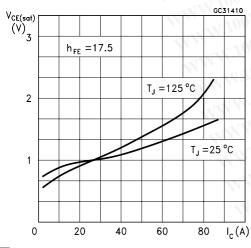
Safe Operating Areas



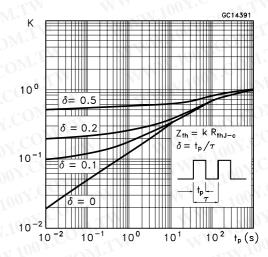
Derating Curve



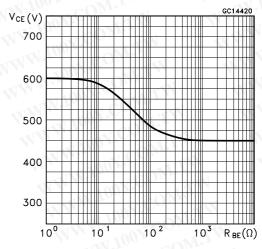
Collector Emitter Saturation Voltage



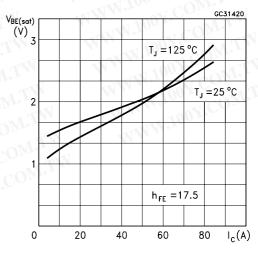
Thermal Impedance



Collector-emitter Voltage Versus base-emitter Resistance



Base-Emitter Saturation Voltage

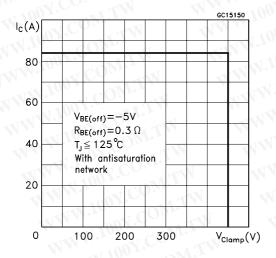


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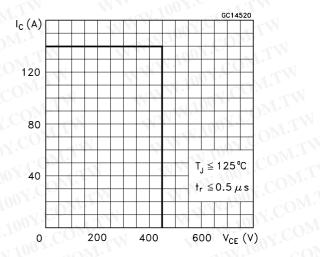
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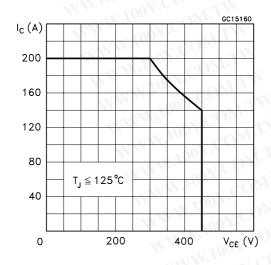
Reverse Biased SOA



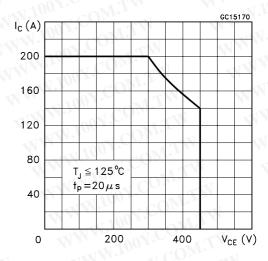
Foward Biased SOA



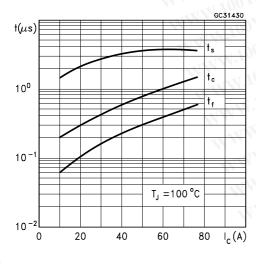
Reverse Biased AOA



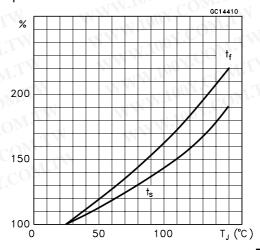
Forward Biased AOA



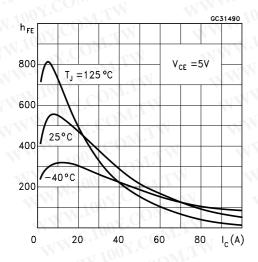
Switching Times Inductive Load



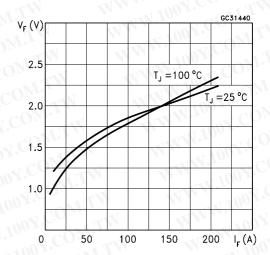
Switching Times Inductive Load Versus Temperature



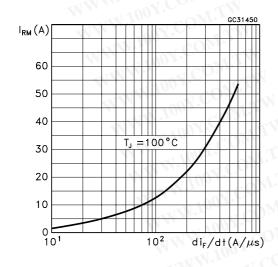
Dc Current Gain



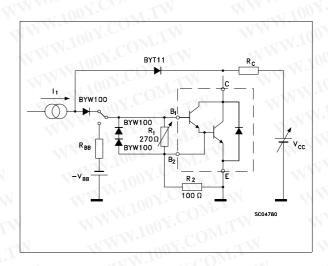
Typical V_F Versus I_F



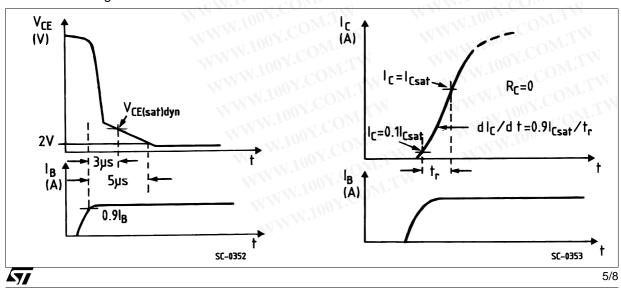
Peak Reverse Current Versus di_F/dt



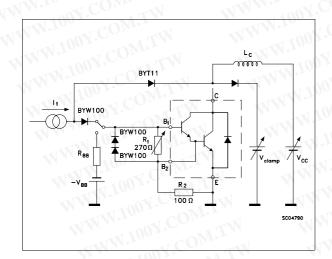
Turn-on Switching Test Circuit



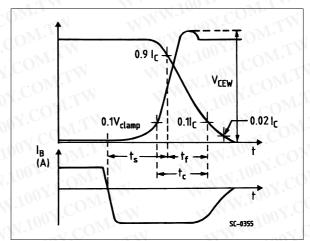
Turn-on Switching Waveforms



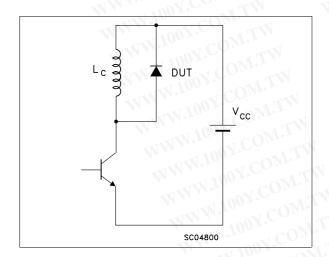
Turn-on Switching Test Circuit



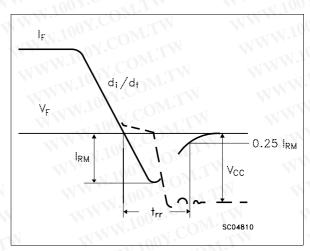
Turn-off Switching Waveforms



Turn-off Switching Test Circuit of Diode



Turn-off Switching Waveform of Diode



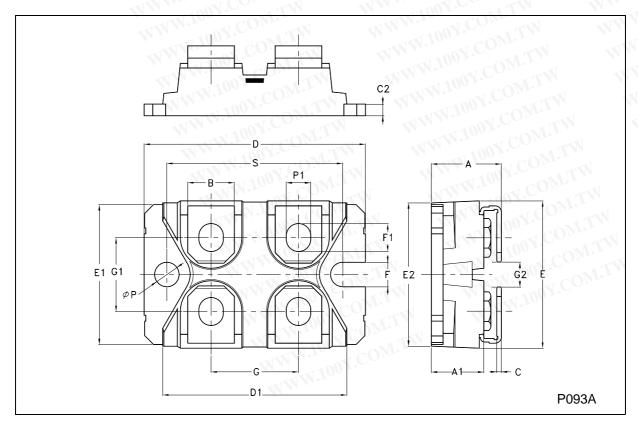
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ISOTOP MECHANICAL DATA

				-47			
DIM.	mm W.1003.			inch			
M DIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
A	11.8	WW	12.2	0.465	WWW	0.480	
A1	8.9	Wir	9.1	0.350	MMM.	0.358	
B 100	7.8		8.2	0.307		0.322	
W C	0.75		0.85	0.029		0.033	
C2	1.95	W W	2.05	0.076	M.M.	0.080	
D.VV.	37.8		38.2	1.488	WW	1.503	
D1	31.5	1. 1.	31.7	1.240	V	1.248	
E	25.15	TW	25.5	0.990		1.003	
E1	23.85	WT	24.15	0.938	n w	0.950	
E2	W.T. CO	24.8	MMM	OUX COL	0.976	100	
G	14.9	MI	15.1	0.586		0.594	
G1	12.6	$O_{M,I,A}$	12.8	0.496	. 1	0.503	
G2 🔨	3.5	WILMS	4.3	0.137	T.T.	1.169	
F	4.1	COM	4.3	0.161	WILL	0.169	
F1	4.6	COM	5	0.181	TW	0.196	
Р	4	COM	4.3	0.157	OM.	0.169	
P1	4 10	Y. OM.T	4.4	0.157	OM:IV	0.173	
S	30.1	OY.CO	30.3	1.185	TIME	1.193	



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